## **General Purpose Transistors**

#### **NPN Silicon**

This transistor is designed for general purpose amplifier applications. It is housed in the SOT-416/SC-75 package which is designed for low power surface mount applications.

#### **Features**

• Pb-Free Package is Available

#### **MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V <sub>CEO</sub>	40	Vdc
Collector – Base Voltage	V <sub>CBO</sub>	60	Vdc
Emitter – Base Voltage	V <sub>EBO</sub>	6.0	Vdc
Collector Current – Continuous	Ic	200	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit -	
Total Device Dissipation, FR-4 Board (Note 1) @T <sub>A</sub> = 25°C Derated above 25°C	PDC	200 1.6	mW mW/°C	
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	600	°C/W	
Total Device Dissipation, FR-4 Board (Note 2) @T <sub>A</sub> = 25°C Derated above 25°C	PD	300 2.4	mW mW/°C	
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	400	°C/W	
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- 1. FR-4 @ Minimum Pad
- 2. FR-4 @ 1.0 × 1.0 Inch Pad

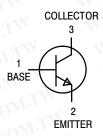
勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw



#### ON Semiconductor

http://onsemi.com

# GENERAL PURPOSE AMPLIFIER TRANSISTORS SURFACE MOUNT





SOT-416/SC-75 CASE 463 STYLE 1

#### **MARKING DIAGRAM**



AM = Device Code
M = Date Code\*

• = Pb-Free Package

(Note: Microdot may be in either location)
\*Date Code orientation may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

9	Device	Package	Shipping <sup>†</sup>		
	MMBT3904TT1	SOT-416	3000 Tape & Reel		
	MMBT3904TT1G	SOT-416 (Pb-Free)	3000 Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## WWW.100Y. MMBT3904TT1

## WWW.100Y.COM.TW 100Y.COM.TW **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

ELECTRICAL CHARACTERISTICS (T. 2000)				
ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25°C unless otherwise noted)  Characteristic	Symbol	Min	Max	Unit
Characteristic  OFF CHARACTERISTICS	Symbol	NIII )	Iviax	Unit
	V	40	).~ [_c()	Vdc
Collector – Emitter Breakdown Voltage (Note 3) $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	V <sub>(BR)CEO</sub>	-40 -40	01.50	Vac
Collector – Base Breakdown Voltage ( $I_C = 10 \mu Adc$ , $I_E = 0$ )	V <sub>(BR)</sub> CBO	60 -40	00 <u>7</u> .0	Vdc
Emitter – Base Breakdown Voltage (I <sub>E</sub> = 10 μAdc, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	6.0 -5.0	10-01	Vdc
Base Cutoff Current (V <sub>CE</sub> = 30 Vdc, V <sub>EB</sub> = 3.0 Vdc)	I <sub>BL</sub>	I <sub>BL</sub> – 50 – 50		nAdc
Collector Cutoff Current (V <sub>CE</sub> = 30 Vdc, V <sub>EB</sub> = 3.0 Vdc)	I <sub>CEX</sub>	4/1	50 -50	nAdc
ON CHARACTERISTICS (Note 3)	OM.	11/	MMT	CO.
DC Current Gain	h <sub>FE</sub>	40 70 100 60 30	300	100X.
Collector – Emitter Saturation Voltage ( $I_C = 10 \text{ mAdc}$ , $I_B = 1.0 \text{ mAdc}$ ) ( $I_C = 50 \text{ mAdc}$ , $I_B = 5.0 \text{ mAdc}$ )	V <sub>CE(sat)</sub>	N -	0.2 0.3	Vdc
Base – Emitter Saturation Voltage ( $I_C = 10 \text{ mAdc}$ , $I_B = 1.0 \text{ mAdc}$ ) ( $I_C = 50 \text{ mAdc}$ , $I_B = 5.0 \text{ mAdc}$ )	V <sub>BE(sat)</sub>	0.65	0.85 0.95	Vdc
SMALL-SIGNAL CHARACTERISTICS	N. Inc. COL	TW		WWW
Current – Gain – Bandwidth Product (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 20 Vdc, f = 100 MHz)	W 100 ft CO	300	_	MHz
Output Capacitance (V <sub>CB</sub> = 5.0 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>obo</sub>	OM.T	4.0	pF
Input Capacitance ( $V_{EB} = 0.5 \text{ Vdc}$ , $I_{C} = 0$ , $f = 1.0 \text{ MHz}$ )	C <sub>ibo</sub>	COM.	8.0	pF
Input Impedance ( $V_{CE} = 10 \text{ Vdc}$ , $I_{C} = 1.0 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$ )	h <sub>ie</sub>	1.0	10	kΩ
Voltage Feedback Ratio (V <sub>CE</sub> = 10 Vdc, I <sub>C</sub> = 1.0 mAdc, f = 1.0 kHz)	h <sub>re</sub>	0.5	8.0	X 10 <sup>-4</sup>
Small – Signal Current Gain (V <sub>CE</sub> = 10 Vdc, I <sub>C</sub> = 1.0 mAdc, f = 1.0 kHz)	h <sub>fe</sub>	100	400	- W
Output Admittance (V <sub>CE</sub> = 10 Vdc, I <sub>C</sub> = 1.0 mAdc, f = 1.0 kHz)	h <sub>oe</sub>	1.0	40	μmhos
Noise Figure ( $V_{CE}$ = 5.0 Vdc, $I_{C}$ = 100 $\mu$ Adc, $R_{S}$ = 1.0 k $\Omega$ , f = 1.0 kHz)	NF	N.100	5.0	dB
SWITCHING CHARACTERISTICS	N WY	111.	ny.Cu	
Delay Time $(V_{CC} = 3.0 \text{ Vdc}, V_{BE} = -0.5 \text{ Vdc})$ MMBT3904TT	1 t <sub>d</sub>	MAIN	35	
Rise Time $(I_C = 10 \text{ mAdc}, I_{B1} = 1.0 \text{ mAdc})$ MMBT3904TT	1 t <sub>r</sub>	_	35	ns
	4.4		200	
Storage Time $(V_{CC} = 3.0 \text{ Vdc}, I_C = 10 \text{ mAdc})$ MMBT3904TT	1 t <sub>s</sub>	-	200	ns

<sup>3.</sup> Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

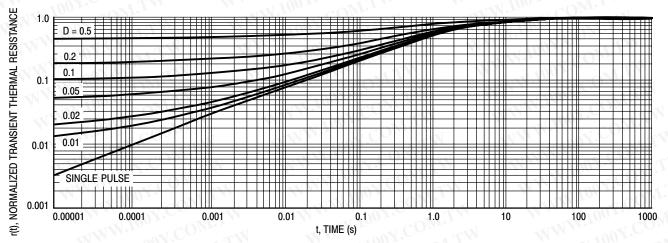
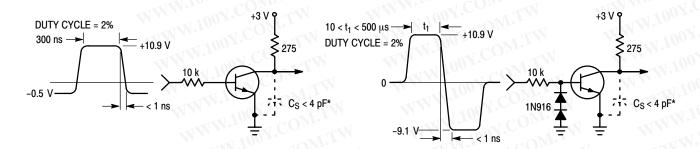


Figure 1. Normalized Thermal Response



\* Total shunt capacitance of test jig and connectors

Figure 2. Delay and Rise Time Equivalent Test Circuit

Figure 3. Storage and Fall Time Equivalent Test Circuit

#### TYPICAL TRANSIENT CHARACTERISTICS

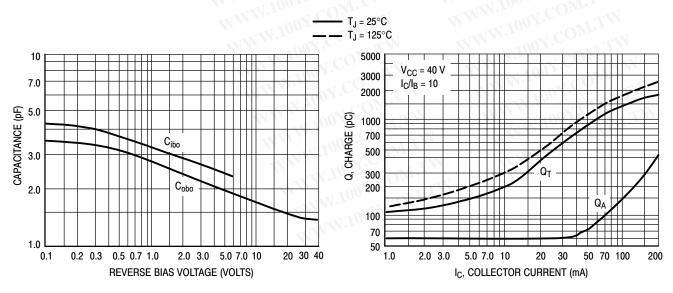
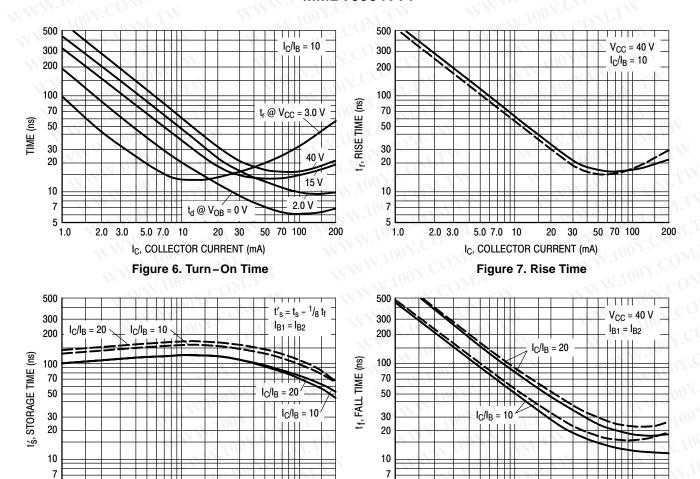


Figure 4. Capacitance

Figure 5. Charge Data



I<sub>C</sub>, COLLECTOR CURRENT (mA)

Figure 8. Storage Time

20 30

50 70 100

5.0 7.0 10

5

1.0

2.0 3.0

I<sub>C</sub>, COLLECTOR CURRENT (mA)

Figure 9. Fall Time

20 30

5.0 7.0 10

50 70 100

## TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

5

1.0

2.0 3.0

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth} = 1.0 \text{ Hz})$ 

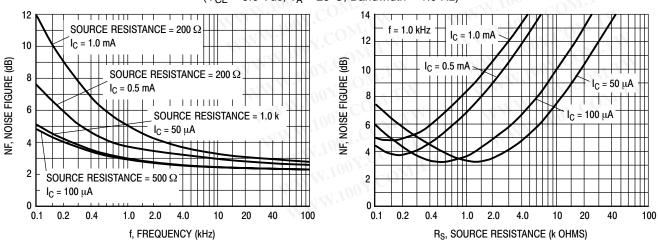
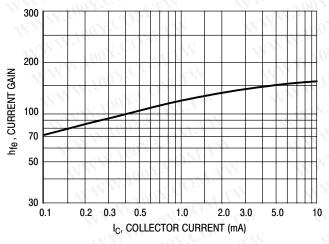


Figure 10. Noise Figure

Figure 11. Noise Figure

#### h PARAMETERS

 $(V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_A = 25^{\circ}\text{C})$ 



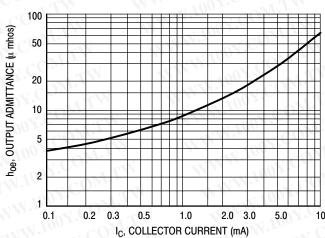
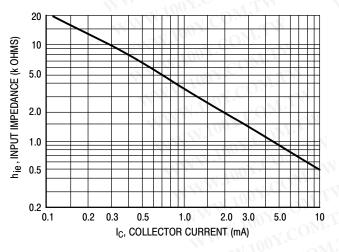


Figure 12. Current Gain

Figure 13. Output Admittance



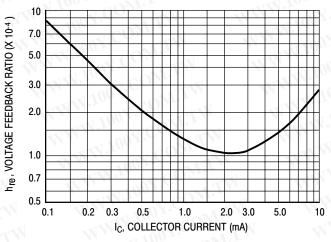


Figure 14. Input Impedance

Figure 15. Voltage Feedback Ratio

#### TYPICAL STATIC CHARACTERISTICS

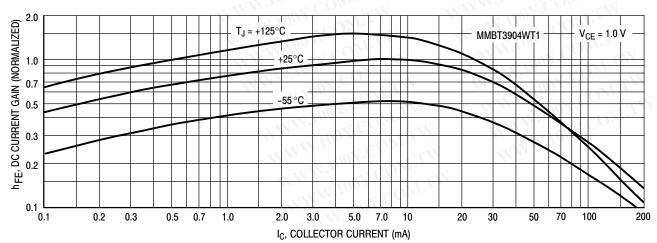


Figure 16. DC Current Gain

## WWW.100Y. MMBT3904TT1

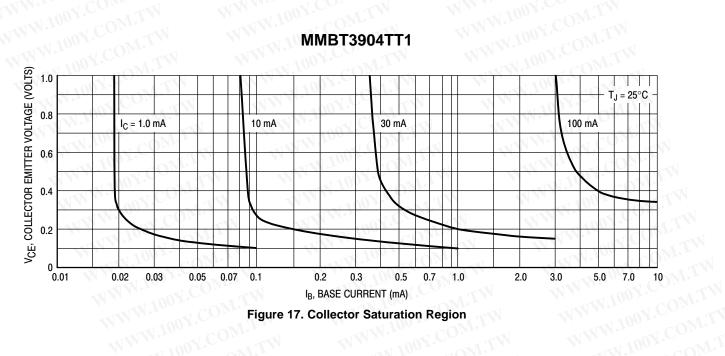


Figure 17. Collector Saturation Region

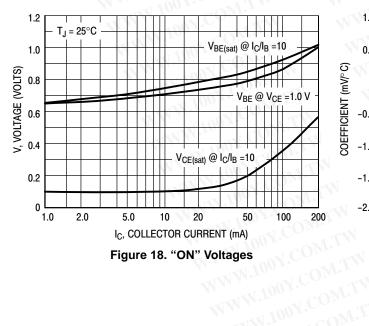


Figure 18. "ON" Voltages

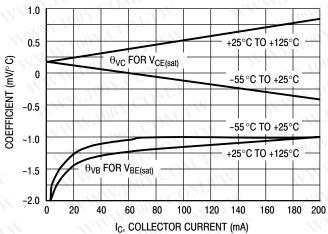
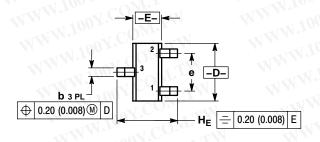
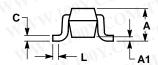


Figure 19. Temperature Coefficients

#### PACKAGE DIMENSIONS

SC-75/SOT-416 CASE 463-01 ISSUE F





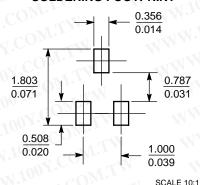
- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.

TX.	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.80	0.90	0.027	0.031	0.035
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.15	0.20	0.30	0.006	0.008	0.012
С	0.10	0.15	0.25	0.004	0.006	0.010
D	1.55	1.60	1.65	0.059	0.063	0.067
Ε	0.70	0.80	0.90	0.027	0.031	0.035
е	1.00 BSC				.04 BS0	
\L\	0.10	0.15	0.20	0.004	0.006	0.008
HE	1.50	1.60	1.70	0.061	0.063	0.065

STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR

(mm inches)

#### SOLDERING FOOTPRINT



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D

> 特力材料886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787

Http://www.100y.com.tw

are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082-1312 USA Phone: 480-829-7710 or 800-344-3860 Toll Free USA/Canada Fax: 480-829-7709 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free

Japan: ON Semiconductor, Japan Customer Focus Center 2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051 Phone: 81-3-5773-3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.